

FMI16N60E

FUJI POWER MOSFET

Super FAP-E³ series

N-CHANNEL SILICON POWER MOSFET

■ Features

Maintains both low power loss and low noise Lower R_{DS}(on) characteristic More controllable switching dv/dt by gate resistance Smaller V_{GS} ringing waveform during switching Narrow band of the gate threshold voltage (3.0±0.5V) High avalanche durability

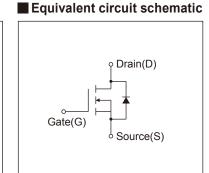
Applications

Switching regulators UPS (Uninterruptible Power Supply) DC-DC converters

Maximum Ratings and Characteristics

● Absolute Maximum Ratings at Tc=25°C (unless otherwise specified)

■ Outline Drawings [mm] T-Pack(L)



Description	Symbol	Characteristics	Unit	Remarks	
Brain Saurea Valtara	V _{DS}	600	V		
Drain-Source Voltage	V _{DSX}	600	V	V _{GS} = -30V	
Continuous Drain Current	In	±16	А		
Pulsed Drain Current	IDP	±64	А		
Gate-Source Voltage	V _{GS}	±30	V		
Repetitive and Non-Repetitive Maximum Avalanche Current	Iar	16	А	Note*1	
Non-Repetitive Maximum Avalanche Energy	Eas	554.8	mJ	Note*2	
Repetitive Maximum Avalanche Energy	Ear	27	mJ	Note*3	
Peak Diode Recovery dV/dt	dV/dt	5.2	kV/μs	Note*4	
Peak Diode Recovery -di/dt	-di/dt	100	A/µs	Note*5	
Maximum Power Dissipation	Po	2.16	10/	Ta=25°C	
		270	W	Tc=25°C	
0	Tch	150	°C		
Operating and Storage Temperature range	T _{stg}	-55 to + 150	°C		

● Electrical Characteristics at Tc=25°C (unless otherwise specified)

Description	Symbol	Conditions	Conditions		typ.	max.	Unit
Drain-Source Breakdown Voltage	BV _{DSS}	I _D =250µA, V _{GS} =0V		600	-	-	V
Gate Threshold Voltage	V _{GS} (th)	I _D =250µA, V _{DS} =V _{GS}		2.5	3.0	3.5	V
Zero Gate Voltage Drain Current		V _{DS} =600V, V _{GS} =0V	Tch=25°C	-	-	25	μA
	IDSS	V _{DS} =480V, V _{GS} =0V	T _{ch} =125°C	-	-	250	
Gate-Source Leakage Current	Igss	V _{GS} =±30V, V _{DS} =0V	V _{GS} =±30V, V _{DS} =0V		10	100	nA
Drain-Source On-State Resistance	R _{DS} (on)	I _D =8A, V _{GS} =10V		-	0.40	0.47	Ω
Forward Transconductance	g _{fs}	I _D =8A, V _{DS} =25V	I _D =8A, V _{DS} =25V		20	-	S
Input Capacitance	Ciss	V _{DS} =25V - V _{GS} =0V - f=1MHz -		-	2650	3980	pF
Output Capacitance	Coss			-	230	345	
Reverse Transfer Capacitance	Crss			17	25.5	1	
Turn-On Time	td(on)	V _{cc} =300V V _{GS} =10V		-	22	33	ns
	tr			-	10	15	
Turn-Off Time	td(off)	ID=8A	ID=8A		120	180	
	tf	R _{GS} =10Ω		-	20	30	
Total Gate Charge	Q _G	Vcc=300V	V _{cc} =300V I _D =16A V _{GS} =10V		76	114	nC
Gate-Source Charge	Qgs	ID=16A			17	25.5	
Gate-Drain Charge	Q _{GD}	V _{GS} =10V			22	33	
Avalanche Capability	lav	L=1.74mH, T _{ch} =25°C		16	-	-	А
Diode Forward On-Voltage	Vsp	I _F =16A, V _{GS} =0V, T _{ch} =25°C		-	0.90	1.35	V
Reverse Recovery Time	trr	I _F =16A, V _{GS} =0V	I _F =16A, V _{GS} =0V		0.7	-	μs
Reverse Recovery Charge	Qrr	-di/dt=100A/µs, Tch=25°C		-	9	-	μC

Thermal Characteristics

Description	Symbol	Test Conditions	min.	typ.	max.	Unit
Thermal resistance	Rth (ch-c)	Channel to case			0.460	°C/W
	Rth (ch-a)	Channel to ambient			62.0	°C/W

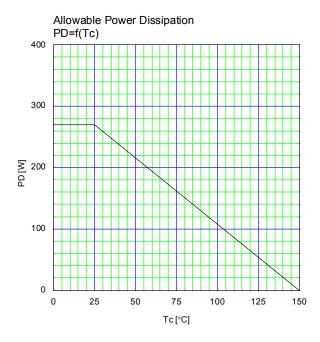
Note *1 : Tch≤150°C

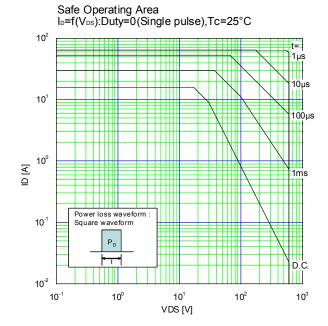
Note 12: Stating Tch=25°C, Ias=7A, L=20.8mH, Vcc=60V, Re=50Ω
Eas limited by maximum channel temperature and avalanche current.
See to 'Avalanche Energy' graph.

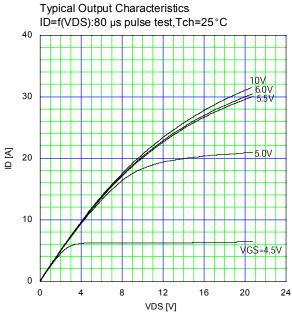
Note $^{\star}3$: Repetitive rating : Pulse width limited by maximum channel temperature.

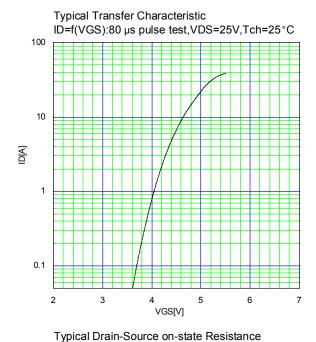
See to the 'Transient Themal impeadance' graph.
Note *4 : Ir≤-Ip, -di/dt=100A/µs, Vcc≤BVbss, Tch≤150°C.

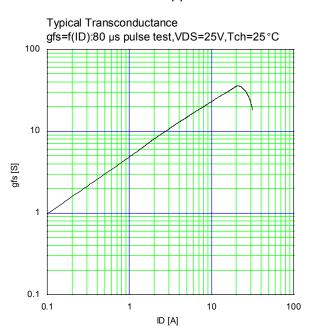
Note *5 : IF≤-ID, dv/dt=5.2kV/µs, Vcc≤BVDss, Tch≤150°C

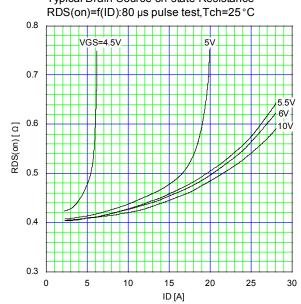


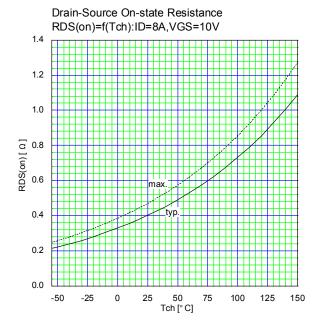


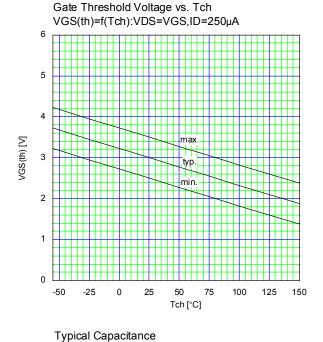


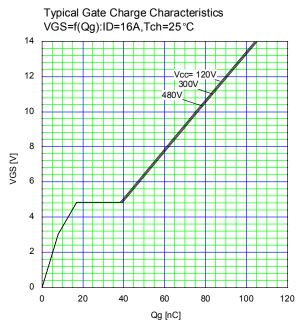


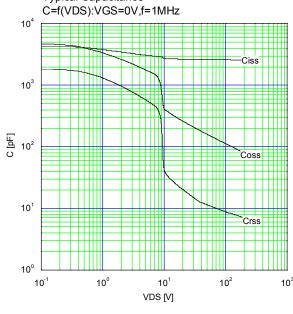


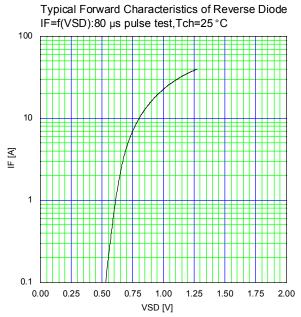


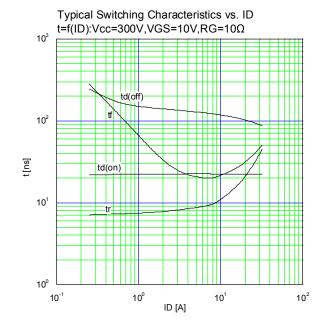




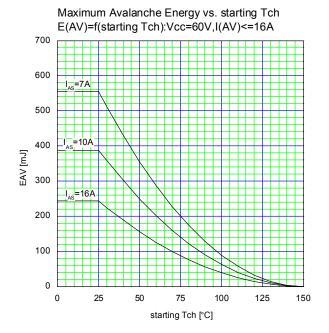


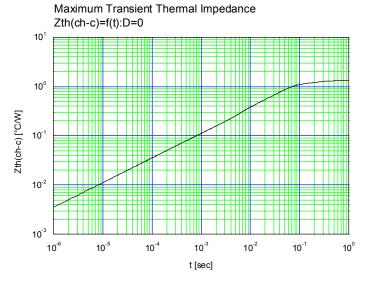






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